## The infrared conductivity of N $a_x$ C oO 2: evidence of gapped states.

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## Abstract

We present infrared ab-plane conductivity data for the layered cobaltate  $Na_xCoO_2$  at three di erent doping levels (x = 0.25;0.50, and 0.75). The D rude weight increases monotonically with hole doping, 1 x. At the lowest hole doping level x= 0.75 the system resembles the normal state of underdoped cuprate superconductors with a scattering rate that varies linearly with frequency and tem perature and there is an onset of scattering by a bosonic mode at 600 cm<sup>-1</sup>. Two higher hole doped samples (x = 0.50 and 0.25) show two di erent-size gaps (110 cm<sup>-1</sup> and 200 cm<sup>-1</sup>, respectively) in the optical conductivities at low tem peratures and become insulators. The spectral weights lost in the gap region of 0.50 and 0.25 samples are shifted to prominent peaks at 200 cm<sup>-1</sup> and 800 cm<sup>-1</sup>, respectively. We propose that the two gapped states of the two higher hole doped samples (x = 0.50 and 0.25) are pinned charge ordered states.

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The recently discovered cobalt oxide superconductor  $N_{ax}CoO_2$  yHO, with 1=4 < x < 1=3and  $y=1.4^{1,2,34}$ , resembles in m any ways that other fam ous fam ily of oxide superconductors, the cuprates. The cobaltate structure is based on two-dimensional planes, weakly coupled in the third direction, the c-axis. The Co ions are on a triangular lattice and calculations based on the t-J m odel suggest that the material may give rise to novel quantum states<sup>5,6</sup>. The  $N_{ax}CoO_2$  material with x = 0.75 appears to be metallic with a Curie-W eiss susceptibility<sup>7,8</sup>. With increased hole doping, 1-x, (sm aller x) the  $N_{ax}CoO_2$  material shows a dimentimental metallic state with a temperature independent paramagnetic susceptibility<sup>8</sup>. Separating the two metallic regions is an insulating state at  $x = 0.50^8$ . In this state a superstructure develops in the N a plane that separates the CoO planes and it has been suggested that the insulating state is induced by this superstructure<sup>8</sup>. O ther charge ordered states that compete with superconductivity have been proposed at higher hole doping levels than  $0.50^{9,10}$ . Here we present optical data that show evidence of two gapped insulating states, one at x = 0.50and a new one at a higher hole doping level close to x = 0.25.

We use optical spectroscopy to investigate the low-lying states of the norm al state of N  $a_x C \circ O_2$  at three di erent doping levels (x = 0.75, 0.50, and 0.25) at various temperatures. P revious optical work has been con ned to the N  $a_x C \circ O_2$  materials with low hole doping levels, x above 0.50 (x = 0.57, 0.70, and 0.82)<sup>11,12,13,14</sup>. A metallic D nude-like absorption is found with anom alous linear frequency dependence of the scattering rate. The infrared rejectance resembles that of the cuprates with the rejectance decreasing linearly with frequency over a broad region extending to nearly 0.75 eV. As the temperature is lowered below room temperature, a knee develops in the rejectance at 600 cm<sup>-1</sup>, characteristic of the interaction of the charge carriers with a bosonic mode<sup>15,16</sup>. We complement this work by extending it to higher hole doping levels, examining electro-chemically doped samples with x = 0.25 and 0.50. We also studied an as-grown sample with x = 0.75.

The preparation of the samples has been described previously<sup>3</sup>. The parent  $Na_xCoO_2$  single crystals are grown by the oating zone method. Na atom swhich reside between the tilted octahedral cobalt oxide layers were deintercalated in a electrochem ical cell. The Na concentration was determined by electron probe microanalysis (EPMA) and we estimate the uncertainty in x to be 0.08. The hole doping of the cobalt oxide layers is thought generally to be proportional to 1 x but it should be noted that there have been reports of other sources carriers such as oxygen de ciency<sup>17,18</sup> or interlayer oxonium ion<sup>19,20,21</sup> making

the N a concentration a less reliable indicator of the in-plane doping level. A swe will show below a more direct measure of doping is the D rude spectral weight which we will use as our main guide in determining the planar hole concentration.

The optical experiments were performed on freshly cleaved ab-plane surface of 2  $2 \text{ mm}^2$  crystals in a <sup>4</sup>He ow cryostat. The ab-plane relectance was measured between 50 and 40 000 cm<sup>-1</sup> using an in situ gold evaporation method<sup>22</sup>. We estimate the absolute accuracy of the relectance to be better than 0.5 %. For K ramlers-K ronig (KK) analysis we used the dc resistivity<sup>23</sup> to extend the data at low frequency. At high frequencies we used a data of C aim i et al.<sup>14</sup> between 40 000 cm<sup>-1</sup>.

Fig. 1a shows the overall re-ectance at each of the three doping levels at room temperature. The re-ectance has a characteristic linear variation with frequency with the slope of the curve decreasing as the materials become more metallic at the higher hole doping levels. This is similar to what happens in the cuprates where the re-ectance slope can be used as an internal standard of the doping level<sup>24</sup>. Using this criterion, we can see that three di-erent samples show re-ectances that follow the Na doping levels monotonically.

Fig. 1b shows the frequency dependent conductivity at room temperature at the three doping levels obtained by KK analysis of the relectance. The dc resistivity is marked on the ordinate axis. We see a low frequency D rude-like band but with a high frequency tail that could be interpreted as an additional absorption band in the mid-infrared. Following W ang et al.<sup>12</sup> we will call this the band. A second prominent band, the band can be seen at 15 000 cm<sup>-1</sup> as well as a third one at 26 000 cm<sup>-1</sup>. We see that as the hole doping level increases there is a strong growth of both the and the band intensities as well as the D rude weight.

The monotonic variation of D nude weight with doping is illustrated in Fig. 1c where we show the partial spectral weight, obtained by integrating the optical conductivity,  $N_{eff}$  (! c) =  $2m V_{Co} = (e^2)_{0}^{R_{1c}} 1$  (!)d!, where m is the mass of an electron,  $V_{Co}$  is the volum eper C o atom, e is the charge of an electron, and 1 is the optical conductivity. The at region between 5000 to 8000 cm<sup>-1</sup> separates the D nude weight from the band weight. The gure shows that the D nude weight grows monotonically with hole doping and that the D nude absorption becomes sharper and hence better de ned as the hole doping level increases. View ed in this high frequency region and at room temperature, the system becomes more metallic with

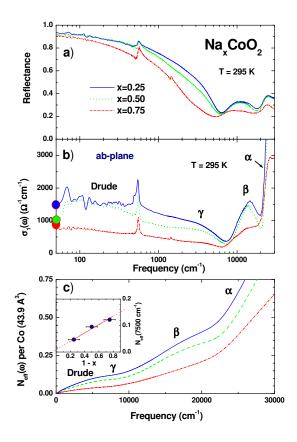


FIG.1: a) The ab-plane relectance of  $Na_x CoO_2$  at three doping levels, at room temperature. b) The ab-plane optical conductivity of  $Na_x CoO_2$  at the three doping levels at room temperature. W e see a broad D rude-like band at low frequency in all sam ples characteristic of an overall metallic conductivity. At higher frequency there are bands denoted and . There is a rapid grow th of spectral weight of the low lying bands and with doping. c) Partial sum rule for the three doping levels. The D rude weight grows monotonically with hole doping, shown by the at region between 5000 cm<sup>-1</sup> and 8000 cm<sup>-1</sup>. The inset shows the spectral weight integrated up to 7500 cm<sup>-1</sup> with error bars 3 % as a function of hole doping with error bars 0.08.

hole doping. However, as we will see, at low frequency and low temperature the two more highly hole-doped samples (x = 0.50 and 0.25) are actually insulators. It is interesting to note that there is no transfer of spectral weight from the ; and bands to the D rude component as the hole doping level is increased as seen in the La<sub>2 x</sub> Sr<sub>x</sub>CuO<sub>4</sub> cuprates<sup>25</sup>.

The optical properties of the 0.75 sample resemble those of the underdoped cuprates superconductors. Fig. 2a shows the optical conductivity of the x = 0.75 sample at a series of tem peratures, from 295 K to 28 K. At room tem perature we see a broad D rude-like band

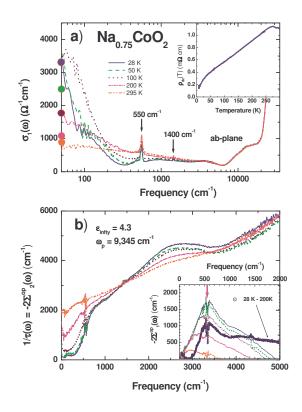


FIG. 2: a) The temperature dependence of the ab-plane optical conductivity of the x = 0.75 sam ple and dc resistivity in the inset. b) The scattering rate 1= . Here we subtracted the phonons at 550 and 1400 cm<sup>-1</sup> to see the bosonic mode better<sup>16</sup>. The inset shows the imaginary part of the optical scattering rate or the real part of the optical self-energy. The contribution of the bosonic mode can be separated from the broad background scattering.

which splits at low temperature into two components, a zero-frequency-centered coherent band and a broad band at 1000 cm<sup>-1</sup> separated by a slight gap-like depression in the 300 cm<sup>-1</sup> region. We also observe two phonons at 550 and 1400 cm<sup>-1</sup>. D raw ing on our experience in the cuprates, we can better illustrate the physics involved here by plotting the real and in aginary parts of the scattering rate (or the optical self-energy) using the extended D rude model<sup>16,26</sup>, shown in Fig. 2b and the inset. Here  $_1(!) = !_p^2 = [4 (! 2^{op}(!))]$ , where  $!_p$ is the plasm a frequency and  $^{op}(!) = {}_1^{op}(!) + i {}_2^{op}(!)$  is the complex optical self-energy. Two phonons at 550 and 1400 cm<sup>-1</sup> have been removed to allow us to see the bosonic mode better. Note that the scattering rate is always greater than the frequency and there are no coherent quasiparticles except perhaps at the low est tem peratures. We also see that the low – frequency scattering is dom inated by a bosonic mode with an onset frequency of scattering of the order of 600 cm<sup>-1</sup>. The contribution of the m ode weakens as the tem perature increases and the scattering is dom inated by a strong linear-in-frequency process, very m uch like that in the cuprates<sup>16</sup>. In this picture of a linear background and a m ode, the dc resistivity shows a positive curvature in the tem perature region where the m ode becomes activated<sup>27</sup>. The m ode and the background can be separated by plotting the imaginary part of the scattering rate or the real part of the optical self-energy<sup>16</sup>, shown in the inset, along with a di erence spectrum where we have subtracted the 200 K spectrum from the 28 K spectrum. The m ode can be seen as a sharp peak around 600 cm<sup>-1</sup> superim posed on the broad background. This line shape is very sim ilar to what is seen in the underdoped cuprates<sup>16</sup>. At low tem peratures the the scattering rate spectrum develops a broad peak at 3000 cm<sup>-1</sup>. This is rem iniscent of the m id-infrared absorption seen in the single layer cuprates at low doping levels<sup>25</sup>.

Fig. 3a shows the frequency dependent conductivity of the x = 0.50 sample at various tem peratures. We show the dc conductivity on the zero frequency axis as well. The dc resistivity shows insulating behavior with the 53 K and 88 K anom alies (see inset of Fig. 3a). We notice that there is an overall agreem ent between the lowest measured infrared conductivity and the dc conductivity. This is evidence of two important facts. First, the samples are reasonably hom ogeneous without any channels and inhom ogeneities that might short circuit the current. Second, there are no low -lying collective modes in the spectral region between zero frequency and 50 cm<sup>1</sup>, our lowest measured frequency. This is not always the case in strongly correlated systems. In the one-dimensional organic conductors there is a large discrepancy between the highly metallic dc conductivity and nearly insulating gap-like behavior in the infrared, a signature of sliding charge-density wave (CDW) transport<sup>28</sup>. There is no evidence for such e ects in our samples of N  $a_x$  C oO  $_2$  , although is should be noted that there is about a factor of two discrepancy between the dc values and the peak that develops around 100 cm<sup>-1</sup>. This is similar to what is seen in the cuprates at low frequency and has been attributed to localization e ects<sup>29</sup>. There is evidence of similar localization e ects in the x = 0.75 sample where there is also a discrepancy at low temperature between the dc and the lowest far infrared measurement and the dc conductivity. In all cases the dc value is lower suggesting localization, whereas in the CDW system s with sliding waves, the dc value is higher by a substantial factor.

This system shows very interesting temperature dependent properties at low frequencies as expected from the temperature dependence of the dc resistivity. There is a sharpening of

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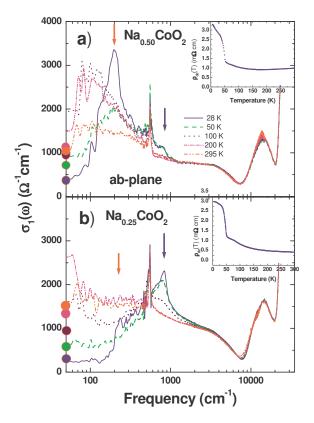


FIG.3: a) Tem perature dependence of the optical ab-plane conductivity of the x = 0.50 sam ple and its dc resistivity in the inset. b) The optical conductivity of the x = 0.25 sam ple and its dc resistivity in the inset. The sym bols on the vertical axis denote the dc conductivity of the sam ples. We see that when the tem perature is lowered both sam ples become more insulating due to the form ation of a gap in the spectrum. The spectral weight removed from the gap is transferred to the peaks at higher frequencies delineated by arrow s.

the free carrier peak as the tem perature is lowered from 295 to 200 K. Between 200 and 100 K the spectra do not change much. Below 100 K a gap develops rapidly and is accompanied by a sharp peak at 200 cm<sup>-1</sup>. At our lowest tem perature 28 K the gap seems fully developed with a width 110 cm<sup>-1</sup>. In agreement with this overall energy scale, the spectral weight lost in the gap region is recovered by 600 cm<sup>-1</sup>. These changes in the optical properties are clear evidence of a low temperature pinned density wave phase with a resonance frequency 200 cm<sup>-1</sup>.

Fig. 3b shows the conductivity of the most highly hole doped sample with x = 0.25 at di erent temperatures. Again, there is reasonable agreem ent between the dc and infrared magnitudes of the conductivity suggesting insulating behavior and the absence of sliding

density waves. The dc resistivity also shows insulating behavior with 53 K and 88 K anom alies (see inset of Fig. 3b). Sim ilar 52 K anom aly has been observed in a highly hole doped and fully hydrated sodium cobaltate,  $Na_{0:30}CoO_2$  1.4H2O<sup>4</sup>. The origin of the anom aly in the dc resistivity of high hole doped system s is not clear yet.

The gap-like depression of conductivity below 200 cm<sup>-1</sup> in the x = 0.25 sam ple starts to develop between 200 and 100 K and is nearly fully form ed at 28 K, our lowest measured tem perature. Like the pseudogap seen in c-axis transport in the cuprates, the gap here does not close at tem perature but has a constant width and lls in as the tem perature is raised. There is a notable sharp peak at 800 cm<sup>-1</sup> that grows in parallel with the gap. It starts below 200 K and has its most rapid rate of increase between 100 K and 50 K. There is a transfer of spectral weight from the gap to the peak, and by 1000 cm<sup>-1</sup>, nearly all the spectral weight lost in the gap region has been recovered. The size and the onset tem perature of the gap, the center frequency of the sharp peak, and the spectral weight recovering frequency in the x = 0.25 sam ple are higher than the corresponding ones in the 0.50 sam ple. These factors strongly suggest that there is a distinct and separate pinned CDW insulating phase in the 0.25 system.

It is interesting to note that in the 0.50 sample there is a weak rem nant of the 800 cm<sup>1</sup> m ode suggesting that the sample m ay have an admixture of the 0.25 phase, about 15 % based on the spectral weight of the peaks. Sim ilarly, it is possible that the feature 230 cm<sup>1</sup> seen in the 0.25 sample m ay be related to a m inority phase of the 0.50 peak at 200 cm<sup>1</sup>, about less than 2 % based on the spectral weight of the peaks. The peaks are denoted by arrows in the gures.

The only transverse optic phonon that can be seen in the spectra is a sharp peak at 550 cm<sup>-1</sup>. Its spectral weight (!<sub>p</sub> = 870 cm<sup>-1</sup>) is consistent with what is expected for a phonon that involves oxygen motion. In the x = 0.75 crystal there is an additional phonon mode at 1400 cm<sup>-1</sup> that we attribute to a small amount of carbonate, one of the starting materials of the synthesis process. The 550 cm<sup>-1</sup> mode in the x = 0.50 sample appears to split between 100 K and 50 K. The 550 cm<sup>-1</sup> mode in 0.75 sample does not show any splitting as temperature is lowered. The 550 cm<sup>-1</sup> mode acquires a slight Fano shape below 100 K at the highest hole doping levels. We do not observe, in any of our samples, the dram atically enhanced spectral weight of phase phonons associated with CDW order seen in the organic charge transfer salts<sup>30</sup>.

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There is an alternate explanation of our results on the two insulating samples in terms of two dimensions are principal to the charge density waves with the stronger principal potential dominating at the higher doping level. However, to explain the fact that we have two insulating samples with D rude weight that dimensions by 20 % we have to assume that the insulating region in the phase diagram at x = 0.5 is quite wide. Another possibility that could account for the extra spectral weight in the 0.25 sample is a two-phase system with m etallic drops present in the insulating host. This can be ruled out since such drops would not add to the D rude weight but give a high frequency band at  $!_p = \frac{p}{3}$ .

In sum m ary the optical conductivity of N  $a_x C \circ O_2$  has m any common elements with the cuprate high temperature superconductors but there are also striking di erences. The free carrier absorption is dominated by a continuum of scattering processes that extend to nearly 0.75 eV in energy. For the 0.75 sample, as the temperature is lowered, a bosonic mode appears, very much like the mode that has been attributed to the magnetic resonance in the cuprates<sup>15,16</sup>. The mode even has a frequency close to that of the cuprates.

The two sam pless with the higher hole doping levels (x = 0.50 and 0.25) become insulators at low frequency and low temperature as results of the development of two diment size gaps and pinning resonance peaks that are quite a bit higher than similar features seen in the cuprates<sup>31,32,33</sup>. There are localization elects in the cuprates, but these are hard to observe because of the appearance of the superconducting state<sup>34</sup>. In contrast, in Na<sub>x</sub>CoO<sub>2</sub> the charge ordering potentials are much stronger giving rise to clear gaps in 0.50 and 0.25 materials as well as absorption peaks at quite high frequencies. These may be processes that compete with superconductivity and may be the cause of the absence of superconductivity of Na<sub>x</sub>CoO<sub>2</sub> or the relatively low superconducting transition temperatures of Na<sub>x</sub>CoO<sub>2</sub> system with additional H<sub>2</sub>O layers. On the positive side, it seems that the basic attractive force in the two systems is very similar suggesting that if the competing charge order can be suppressed by them anipulation of the Na lattice a higher superconducting T<sub>c</sub> may be possible in this system.

## A cknow ledgm ents

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